TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

# TLP621,TLP621-2,TLP621-4

Programmable Controller AC / DC-Input Module Solid State Relay

The TOSHIBA TLP621, -2 and -4 consists of a photo-transistor optically coupled to a gallium arsenide infrared emitting diode. The TLP621-2 offers two isolated channels in an eight lead plastic DIP, which the TLP621-4 provides four isolated channels in a sixteen plastic DIP.

- Collector-emitter voltage: 55 V (min.)
- Current transfer ratio: 50% (min.)

Rank GB: 100% (min.)

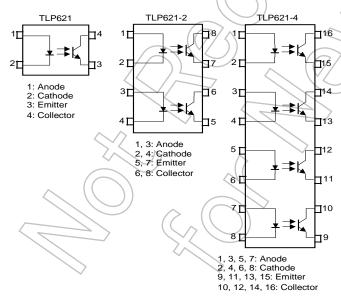
- Isolation voltage: 5000Vrms(min)
- UL recognized: UL1577, file No. E67349
- cUL approved: CSA Component Acceptance Service No.5A,

file No. E67349

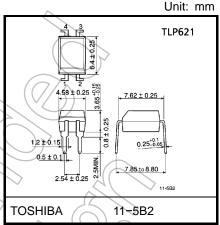
• Option (D4) type VDE approved: DIN EN60747-5-5 (Note 1)

(Note 1) When an EN60747-5-5 approved type is needed, please designate "Option (D4)."

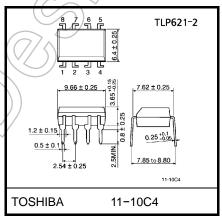
#### Pin Configurations (top view)



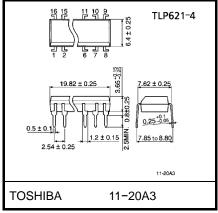
|   |                      | 7.62 mm pitch                      | 10.16 mm pitch<br>TLPxxxF type |
|---|----------------------|------------------------------------|--------------------------------|
|   |                      | standard type                      | TLPxxxF type                   |
| • | Creepage distance    | : 6.4 mm (min.)                    | 8.0 mm (min)                   |
|   | Clearance            | : 6.4 mm (min.)                    | 8.0 mm (min)                   |
|   | Insulation thickness | : 0.4 mm (min.)                    | 0.4 mm (min)                   |
|   | Clearance            | : 6.4 mm (min.)<br>: 0.4 mm (min.) | 8.0 mm (min)<br>0.4 mm (min)   |



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Weight: 1.1 g (typ.)

Start of commercial production 1983/02



#### • Current Transfer Ratio

| Туре     | Classi-<br>fication<br>*1 | Current Transfer Ratio (%) (Ic / IF)  IF = 5mA, VCE = 5V, Ta = 25°C |      | Marking Of<br>Classification        |
|----------|---------------------------|---|------|-------------------------------------|
|          |                           | Min.  | Max. |                                     |
|          | (None)                    | 50  | 600  | Blank, Y*, YE, G, G*, GR, B, BL, GB |
|          | Rank Y                    | 50  | 150  | YE, Y⁼                              |
|          | Rank GR                   | 100   | 300  | GR, G, G <sup>■</sup>               |
|          | Rank BL                   | 200   | 600  | BL,B                                |
| TLP621   | Rank GB                   | 100   | 600  | GB, GR, G, G <sup>■</sup> , BL, B   |
|          | Rank YH                   | 75  | 150  | Y•                                  |
|          | Rank GRL                  | 100   | 200  | G                                   |
|          | Rank GRH                  | 150   | 300  | G*                                  |
|          | Rank BLL                  | 200   | 400  | В                                   |
| TLP621-2 | (None)                    | 50  | 600  | Blank, GR, BL, GB                   |
| TLP621-4 | Rank GB                   | 100   | 600  | GB, GR, BL                          |

<sup>\*1:</sup> Ex. rank GB: TLP621 (GB)

(Note) Application type name for certification test, please use standard product type name, i.e.

TLP621 (GB): TLP621 TLP621-2 (GB): TLP621-2



#### **Absolute Maximum Ratings (Ta = 25°C)**

|  |   |                     | Ra                      | ting                 |                  |
|--|---|---------------------|-------------------------|----------------------|------------------|
|  | Characteristic  | Symbol              | TLP621                  | TLP621-2<br>TLP621-4 | Unit             |
|  | Forward current   | lF                  | 60                      | 50                   | mA               |
|  | Forward current derating (Note 1)                           | ΔI <sub>F</sub> /°C | -0.7 (Ta ≥ 39°C)        | –0.5 (Ta ≥ 25°C)     | mA /°C           |
|  | Pulse forward current                                       | IFP                 | 1 (100μs pulse, 100pps) |                      | A                |
| LED  | Power dissipation   | PD                  | 100                     | 70                   | mW               |
|  | Power dissipation derating                                  | ΔP <sub>D</sub> /°C | -1.0                    | -0.7                 | mW /°C           |
|  | Reverse voltage   | VR                  |                         |                      | V                |
|  | Junction temperature  | Tj                  | 12                      | 25                   | °C               |
|  | Collector-emitter voltage                                   | VCEO                | 5                       | 55                   |                  |
|  | Emitter-collector voltage                                   | VECO                |                         |                      | V                |
| 5  | Collector current   | Ic                  | 50                      |                      | mΑ               |
| Detector   | Collector power dissipation (1 circuit)                     | PC                  | 150                     | 100                  | mW               |
|  | Collector power dissipation derating (1 circuit, Ta ≥ 25°C) | ΔP <sub>C</sub> /°C | 1.5                     | -1.0                 | mW /°C           |
|  | Junction temperature  | Tj                  | 1:                      | 25                   | \>c              |
| Stor   | age temperature range                                       | T <sub>stg</sub>    | −55 t                   | 0 125                | ) °C             |
| Ope  | erating temperature range                                   | T <sub>opr</sub> (  | -55 to 100              |                      | °C               |
| Lea  | d soldering temperature                                     | T <sub>sol</sub>    | 260 (10 s)              |                      | °C               |
| Tota   | al package power dissipation                                | PT                  | 250                     | 150                  | mW               |
| Total package power dissipation derating (Ta ≥ 25°C) |   | ΔP <sub>T</sub> /°C | -2.5                    | 1.5                  | mW /°C           |
| Isola  | ation voltage (Note 2)                                      | BVs                 | 5000 (AC, 1mi           | n., R.H.≤ 60%)       | V <sub>rms</sub> |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $Pw = 100 \mu s(max)$ , f = 100 Hz

Note 2: Device considered a two terminal: LED side pins shorted together, and detector side pins shorted together.

### **Recommended Operating Conditions**

| Characteristic        | Symbol           | Min. | Тур. | Max. | Unit |
|-----------------------|------------------|------|------|------|------|
| Supply voltage        | Vcc              | _    | 5    | 24   | V    |
| Forward current       | lF               | _    | 16   | 20   | mA   |
| Collector current     | IC               | _    | 1    | 10   | mA   |
| Operating temperature | T <sub>opr</sub> | -25  | _    | 85   | °C   |

Note: Recommended operating conditions are given as a design guideline to obtain expected performance of the device. Additionally, each item is an independent guideline respectively. In developing designs using this product, please confirm specified characteristics shown in this document.



### Individual Electrical Characteristics (Ta = 25°C)

|          | Characteristic                         | Symbol                 | Test Condition                     | Min. | Тур.    | Max. | Unit |
|----------|--|------------------------|------------------------------------|------|---------|------|------|
|          | Forward voltage                        | VF                     | IF = 10 mA                         | 1.0  | 1.15    | 1.3  | V    |
| LED      | Reverse current                        | I <sub>R</sub>         | V <sub>R</sub> = 5 V               | _    | _       | 10   | μΑ   |
|          | Capacitance                            | Ст                     | V = 0 V, f = 1 MHz                 | 7    | 30      | _    | pF   |
|          | Collector-emitter breakdown voltage    | V <sub>(BR)</sub> CEO  | I <sub>C</sub> = 0.5 mA            | 55   | 4       |      | ٧    |
| ctor     | Emitter-collector<br>breakdown voltage | V <sub>(BR)</sub> ECO  | I <sub>E</sub> = 0.1 mA            | ),   | )<br> - |      | V    |
| Detector | Collector dark current ICFO            | V <sub>CE</sub> = 24 V | <del>)</del>                       | 10   | 100     | nA   |      |
|          | Collector dark current                 | ICEO                   | V <sub>CE</sub> = 24 V, Ta = 85 °C |      | 2       | 50   | μΑ   |
|          | Capacitance (collector to emitter)     | C <sub>CE</sub>        | V = 0 V, f = 1 MHz                 |      | 10      |      | pF   |

## Coupled Electrical Characteristics (Ta = 25°C)

| Characteristic         | Symbol                                | Test Condition                                     | MIn. | Тур.    | Max.       | Unit |
|------------------------|---------------------------------------|--|------|---------|------------|------|
| Current transfer ratio | I <sub>C</sub> / I <sub>F</sub>       | $I_F = 5 \text{ mA}, V_{CE} = 5 \text{ V}$ Rank GB | 50   | \       | 600<br>600 | %    |
| Saturated CTR          | I <sub>C</sub> / I <sub>F</sub> (sat) | IF = 1 mA, V <sub>CE</sub> = 0.4 V<br>Rank GB      | 30   | 60<br>— |            | %    |
| Collector-emitter      | VCE (sat)                             | I <sub>C</sub> = 2,4 mA, I <sub>F</sub> = 8 mA     |      | 0.2     | 0.4        | V    |
| saturation voltage     | SE (Sat)                              | Ic = 0.2 mA, IF = 1 mA<br>Rank GB                  | _    | _       | 0.4        | v    |

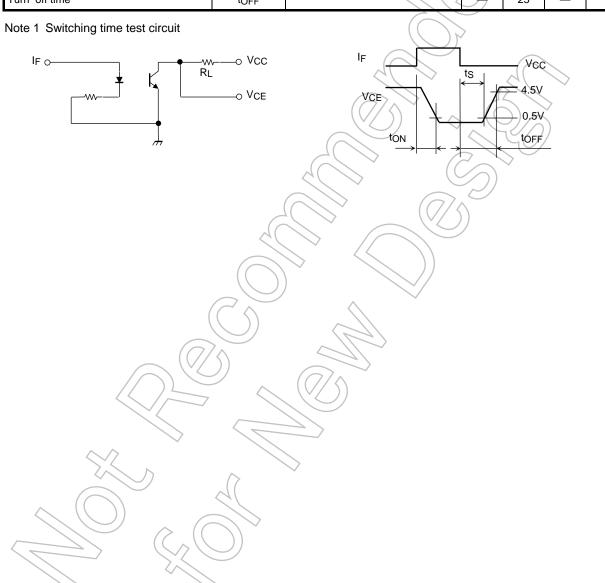
# Isolation Characteristics (Ta = 25°C)

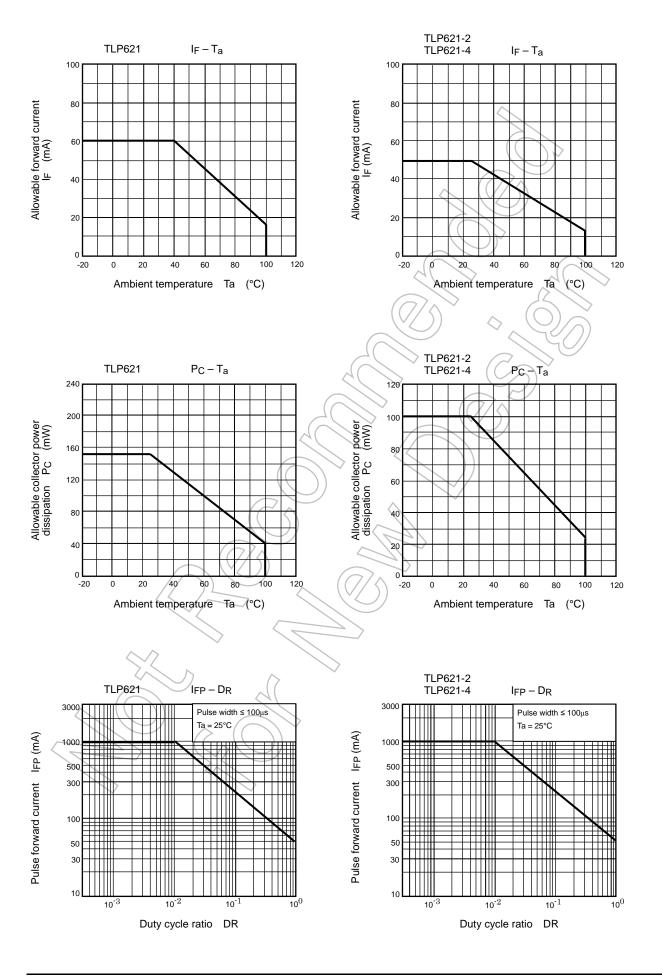
| Characteristic                | Symbol | Test Condition                     | Min.               | Тур.             | Max. | Unit             |
|-------------------------------|--------|------------------------------------|--------------------|------------------|------|------------------|
| Capacitance (input to output) | Cs     | $V_S = 0 V, f = 1 MHz$             | _                  | 0.8              | _    | pF               |
| Isolation resistance          | Rs     | V <sub>S</sub> = 500 V, R.H. ≤ 60% | 1×10 <sup>12</sup> | 10 <sup>14</sup> | _    | Ω                |
|                               |        | AC, 1 minute                       | 5000               | _                | _    | \/               |
| Isolation voltage             | BVs    | AC, 1 second, in oil               | _                  | 10000            | _    | V <sub>rms</sub> |
|                               |        | DC, 1 minute, in oil               | _                  | 10000            |      | $V_{dc}$         |

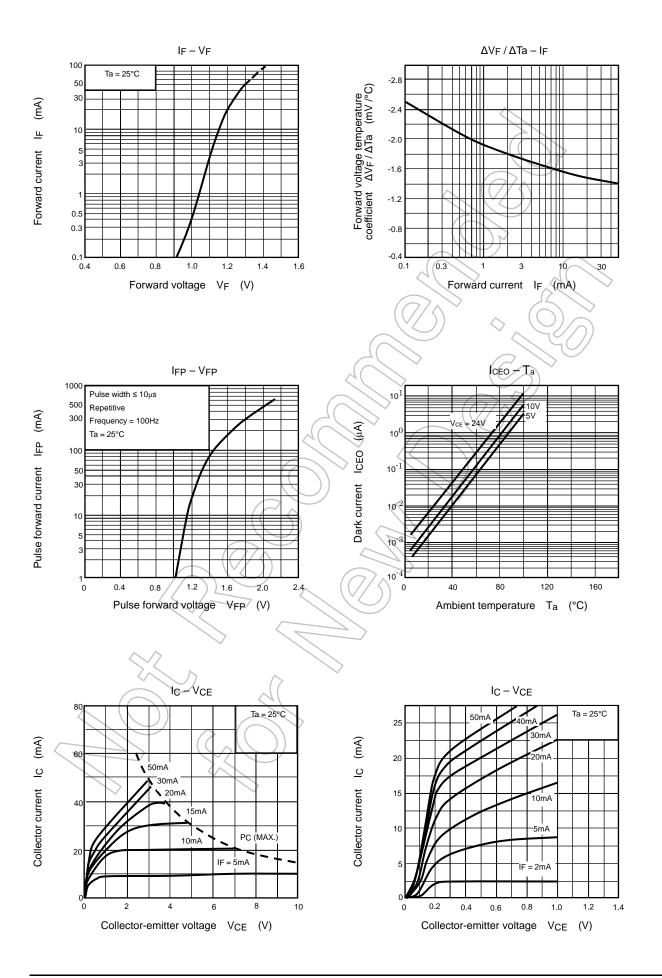


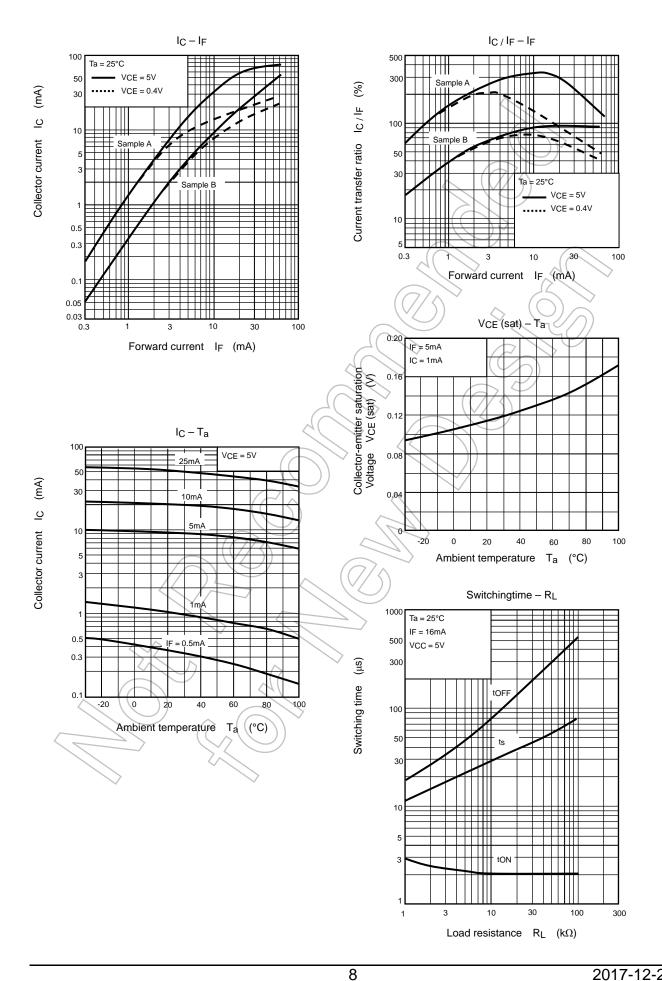
## **Switching Characteristics (Ta = 25°C)**

| Characteristic | Symbol           | Test Condition  | Min.          | Тур.  | Max. | Unit |
|----------------|------------------|---|---------------|-------|------|------|
| Rise time      | t <sub>r</sub>   |   | _             | 2     | _    |      |
| Fall time      | tf               | $V_{CC}$ = 10 V, $I_{C}$ = 2 mA $R_{L}$ = 100 $\Omega$                              | _             | 3     | _    |      |
| Turn-on time   | ton              |   | /             | 3     | _    | μS   |
| Turn-off time  | t <sub>off</sub> |   |               | 3     | _    |      |
| Turn-on time   | ton              |   | 1             | ) / 2 | _    |      |
| Storage time   | ts               | $R_L = 1.9 \text{ k}\Omega$ (Note 1)<br>$V_{CC} = 5 \text{ V}, I_F = 16 \text{ mA}$ | ·/~           | 15    | _    | μS   |
| Turn-off time  | toff             |   | $\mathcal{F}$ | 25    |      |      |









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